

INFORMATION DISCLOSURE CITATION

(Use several sheets if necessary)

Docket Number (Optional)

29288.080

Application Number

09/856,847

#3

Applicant(s)

Akihiro ODAGAWA, et al.

Filing Date

May 25, 2001

Group Art Unit

To be assigned

U.S. PATENT DOCUMENTS

*EXAMINER INITIAL	REF	DOCUMENT NUMBER	DATE	NAME	CLASS	SUBCLASS	FILING DATE IF APPROPRIATE
HN	A	5,448,515	09/05/1995	Fukami, et al.	365	171	—

FOREIGN PATENT DOCUMENTS

	REF	DOCUMENT NUMBER	DATE	COUNTRY	CLASS	SUBCLASS	Translation	
							YES	NO
HN	B	6-73526	03/15/1994	Japan	—	—	✓	✓
HN	C	EP 0 959 475 A2	11/24/1999	EPO	—	—		
HN	D	EP 0 844 679 A1	05/27/1998	EPO	—	—		
HN	E	WO 97/39488	10/23/1997	PCT	—	—		

OTHER DOCUMENTS (Including Author, Title, Date, Pertinent Pages, Etc.)

HN	F	"Quaternary Giant Magnetoresistance Random Access Memory", Zhigang Wang and Yoshihisa Nakamura, Research Institute of Electrical Communication, Tohoku University, Sendai 980, Japan - J. Appl. Phys. 79 (8), 15 April 1996, pp. 6639-6641

EXAMINER

HIEN NGUYEN

DATE CONSIDERED

10/8/03

EXAMINER: Initial if citation considered, whether or not citation is in conformance with MPEP Section 609; Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.